MMBTA42LT1, MMBTA43LT1

MMBTA42LT1 is a Preferred Device

High Voltage Transistors

NPN Silicon

Features

• Pb-Free Packages are Available

MAXIMUM RATINGS

Characteristic		Symbol	Value	Unit
Collector-Emitter Voltage	MMBTA42 MMBTA43	V _{CEO}	300 200	Vdc
Collector-Base Voltage	MMBTA42 MMBTA43	V _{CBO}	300 200	Vdc
Emitter-Base Voltage	MMBTA42 MMBTA43	V _{EBO}	6.0 6.0	Vdc
Collector Current - Continuous	3	Ic	50	mAdc

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board (Note 1) T _A = 25°C Derate above 25°C	P _D	225 1.8	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	556	°C/W
Total Device Dissipation Alumina Substrate (Note 2) T _A = 25°C Derate above 25°C	P _D	300 2.4	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	417	°C/W
Junction and Storage Temperature	T _J , T _{stg}	- 55 to +150	°C

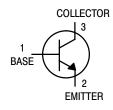
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

- 1. FR-5 = $1.0 \times 0.75 \times 0.062$ in.
- 2. Alumina = 0.4 x 0.3 x 0.024 in. 99.5% alumina.



ON Semiconductor®

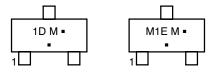
http://onsemi.com





SOT-23 (TO-236) CASE 318 STYLE 6

MARKING DIAGRAM



1D = MMBTA42LT M1E = MMBTA43LT M = Date Code* • = Pb-Free Package

(Note: Microdot may be in either location)

*Date Code orientation and/or overbar may vary depending upon manufacturing location.

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 3 of this data sheet.

Preferred devices are recommended choices for future use and best overall value.

MMBTA42LT1, MMBTA43LT1

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit	
OFF CHARACTERISTICS				•	•
Collector-Emitter Breakdown Voltage (Note 3) $(I_C = 1.0 \text{ mAdc}, I_B = 0)$	MMBTA42 MMBTA43	V _{(BR)CEO}	300 200	- -	Vdc
Collector-Base Breakdown Voltage ($I_C = 100 \mu Adc, I_E = 0$)	MMBTA42 MMBTA43	V _{(BR)CBO}	300 200	- -	Vdc
Emitter-Base Breakdown Voltage ($I_E = 100 \mu Adc, I_C = 0$)		V _{(BR)EBO}	6.0	-	Vdc
Collector Cutoff Current $(V_{CB} = 200 \text{ Vdc}, I_E = 0)$ $(V_{CB} = 160 \text{ Vdc}, I_E = 0)$	MMBTA42 MMBTA43	I _{CBO}	-	0.1 0.1	μAdc
Emitter Cutoff Current	MMBTA42 MMBTA43	I _{EBO}	-	0.1 0.1	μAdc
ON CHARACTERISTICS (Note 3)					
DC Current Gain ($I_C = 1.0 \text{ mAdc}$, $V_{CE} = 10 \text{ Vdc}$) ($I_C = 10 \text{ mAdc}$, $V_{CE} = 10 \text{ Vdc}$)	Both Types Both Types	h _{FE}	25 40	-	-
$(I_C = 30 \text{ mAdc}, V_{CE} = 10 \text{ Vdc})$	MMBTA42 MMBTA43		40 40	-	
Collector-Emitter Saturation Voltage (I _C = 20 mAdc, I _B = 2.0 mAdc)	MMBTA42 MMBTA43	V _{CE(sat)}	- -	0.5 0.5	Vdc
Base-Emitter Saturation Voltage (I _C = 20 mAdc, I _B = 2.0 mAdc)		V _{BE(sat)}	-	0.9	Vdc
SMALL-SIGNAL CHARACTERISTICS					
Current-Gain - Bandwidth Product (I _C = 10 mAdc, V _{CE} = 20 Vdc, f = 100 MHz)		f _T	50	-	MHz
Collector-Base Capacitance (V _{CB} = 20 Vdc, I _E = 0, f = 1.0 MHz)	MMBTA42 MMBTA43	C _{cb}	-	3.0 4.0	pF

^{3.} Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2.0%.

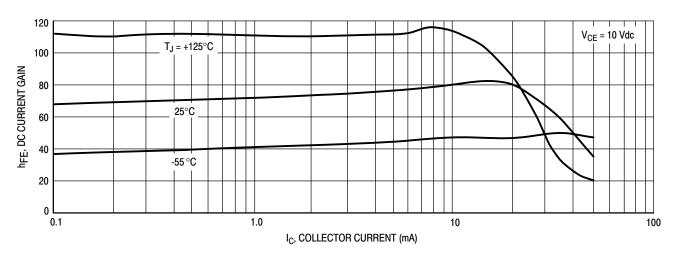


Figure 1. DC Current Gain

MMBTA42LT1, MMBTA43LT1

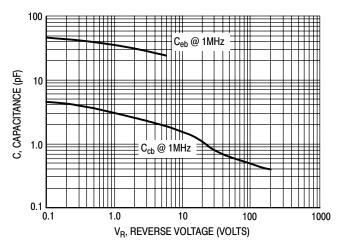


Figure 2. Capacitance

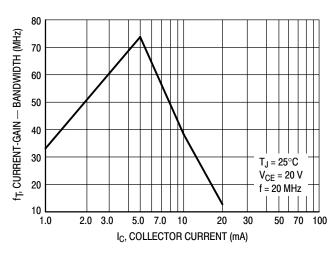


Figure 3. Current-Gain - Bandwidth

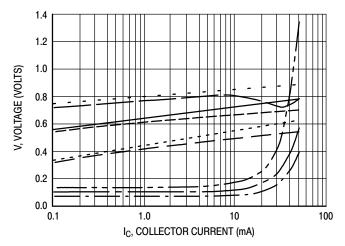
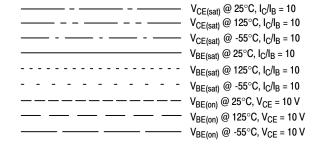


Figure 4. "ON" Voltages



ORDERING INFORMATION

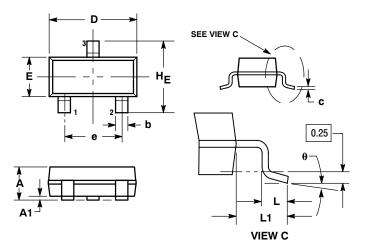
Device Order Number	Package Type	Shipping [†]
MMBTA42LT1	SOT-23	3,000 / Tape & Reel
MMBTA42LT1G	SOT-23 (Pb-Free)	3,000 / Tape & Reel
MMBTA42LT3	SOT-23	10,000 / Tape & Reel
MMBTA42LT3G	SOT-23 (Pb-Free)	10,000 / Tape & Reel
MMBTA43LT1	SOT-23	3,000 / Tape & Reel
MMBTA43LT1G	SOT-23 (Pb-Free)	3,000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MMBTA42LT1, MMBTA43LT1

PACKAGE DIMENSIONS

SOT-23 (TO-236) CASE 318-08 **ISSUE AN**



NOTES

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. CONTROLLING DIMENSION: INCH.
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
- 318-01 THRU -07 AND -09 OBSOLETE, NEW STANDARD 318-08.

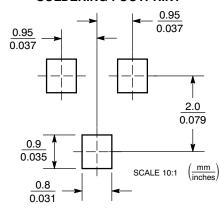
	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.89	1.00	1.11	0.035	0.040	0.044
A1	0.01	0.06	0.10	0.001	0.002	0.004
b	0.37	0.44	0.50	0.015	0.018	0.020
С	0.09	0.13	0.18	0.003	0.005	0.007
D	2.80	2.90	3.04	0.110	0.114	0.120
E	1.20	1.30	1.40	0.047	0.051	0.055
е	1.78	1.90	2.04	0.070	0.075	0.081
L	0.10	0.20	0.30	0.004	0.008	0.012
L1	0.35	0.54	0.69	0.014	0.021	0.029
HE	2.10	2.40	2.64	0.083	0.094	0.104

STYLE 6:

PIN 1. BASE 2. EMITT

- EMITTER
- COLLECTOR

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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